# AC6373B Datasheet

# Zhuhai Jieli Technology Co.,LTD

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## **AC6373B Features**

#### **CPU**

- 32-bit DSP supports hardware Float Point Unit(FPU)
- Up to 160MHz programmable processor
- 64 Vectored interrupts
- 4 Levels interrupt priority

#### **Bluetooth**

- Compliant with BluetoothV5.1+BR+EDR+BLE specification
- Meet class1 class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Provides amaximum+8dbm transmitting power
- receiver with -94dBm sensitivity
- Fast AGC for enhanced dynamic range
- Supports a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gapga tt\rfcomm\sdp\l2cap profile

#### **Peripherals**

- One full speed USB 2.0 OTG controller
- Six multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex basic UART, support DMA

#### mode

- One hardware IIC interface supports host and device mode
- One Built-in low power Cap Sense Keys
- Built-in Cap Sense Key controller
- 10-bit ADC for analog sampling
- External wake up/interrupt on all GPIOs

#### **PMU**

- Low voltage LDO and DC-DC for internal digital and analog circuit supply
- **2uA** current consumption in the soft-off mode
- Built-in LDO and DC-DC for the core, I/O, Bluetooth and flash
- VBAT is 2.2V to 4.5V
- VDDIO is 2.2V to 3.4V

#### **Packages**

QFN20(3mm\*3mm)

#### **Temperature**

- Operating temperature: -40°C to+85°C
- Storage temperature:  $-65^{\circ}$ C to  $+150^{\circ}$ C

#### **Applications**

Bluetooth IOT

## 1, Pin Definition

## 1.1 Pin Assignment

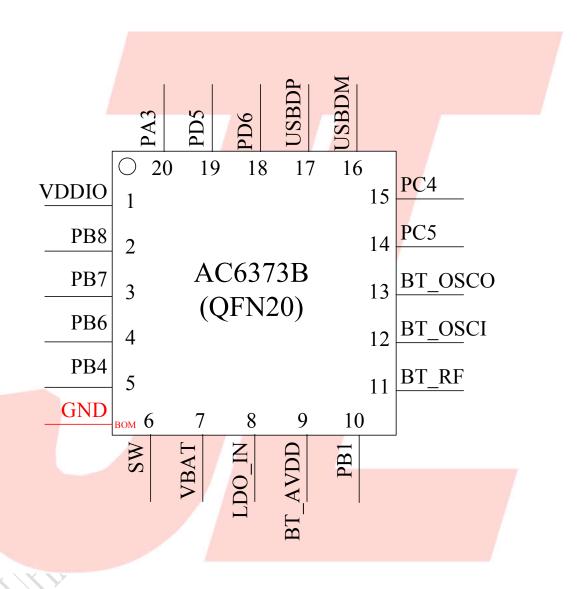


Figure 1-1 AC6373B Package Diagram

## 1.2 Pin Description

Table 1-1 AC6373B Pin Description

PIN NO.	Name	I/O Type	Drive (mA)	Function	Other Function
1	VDDIO	P	/		IO Power 3.3v
2	PB8	I/O	8/24	GPIO	UARTORXB: Uarto Data Input(B); CAP4: Timer4 Capture;
3	PB7	I/O	8/24	GPIO	UARTOTXB: Uart0 Data Output(B); SPI1DOA: SPI1 Data Out(A); Q-decoder1;
4	PB6	I/O	8/24	GPIO	UART1RXA: Uart1 Data Input(A); SPI1CLKA: SPI1 Clk(A); PWM2: Timer2 PWM Output; ADC9: ADC Input Channel 9; Touch7: Touch Input Channel 7; Q-decoder0;
5	PB4	I/O	8/24	GPIO	ADC12: ADC Input Channel 12; TMR2: Timer2 Clock Input;
6	SW	P	/	DCDC output	DCDC switch output, connected to inductor
7	VBAT	P	/		connect to battery
8	LDO_IN	P	/		Charge Power Input; UART0TXC: Uart0 Data Output(C); UART0RXC: Uart0 Data Input(C); PWM3: Timer3 PWM Output; CAP1: Timer1 Capture;
9	BT_AVDD	P	1	/	BT Power
10	PB1	I/O	8/24	GPIO (pull up)	Long Press Reset;  UART2TXC: Uart2 Data Output(C);  ADC6: ADC Input Channel 6;  LP_TH0: Low Power Touch Channel 0;
11	BT_RF	/	/		BT Antenna
12	BT_OSCI	I	/		BTOSC In
13	BT_OSCO	О	/		BTOSC Out
14	PC5	I/O	8/24	GPIO	UART2RXD: Uart2 Data Input(D); SPI1DOB: SPI1 Data Out(B); IIC_SDA_B: IIC SDA(B); ADC5: ADC Input Channel 5;

15	PC4	I/O	8/24	GPIO	UART2TXD: Uart2 Data Output(D);  SPI1CLKB: SPI1 Clk(B);  IIC_SCL_B: IIC SCL(B);  ADC4: ADC Input Channel 4;  PWM4: Timer4 PWM Output; ;
16	USBDM	I/O	4	USB Negative Data (pull down)	UART1RXD: Uart1 Data Input(D);  SPI2DOB: SPI2 Data Out(B);  IIC_SDA_A: IIC SDA(A);  ADC11: ADC Input Channel 11;
17	USBDP	I/O	4	USB Positive Data (pull down)	UARTITXD: Uart1 Data Output(D); SPI2CLKB: SPI2 Clk(B); IIC_SCL_A: IIC SCL(A); ADC10: ADC Input Channel 10;
18	PD6	I/O	8/24	GPIO	
19	PD5	I/O	8/24	GPIO	
20	PA3	I/O	8/24	GPIO	UART2TXA: Uart2 Data Output(A); ADC0: ADC Input Channel 0; PWM1: Timer1 PWM Output; ; Touch0: Touch Input Channel 0;

## 2, Electrical Characteristics

## 2.1 Absolute Maximum Ratings

Table 2-1

Symbol	Parameter	Min	Max	Unit
Tamb	Ambient Temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	4.5	V
LDO_IN	Charger Voltage	-0.3	6	V
V <sub>3.3IO</sub>	3.3V IO Input Voltage	-0.3	3.6	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

## 2.2 Recommended Operating Conditions

Table 2-2

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
VBAT	Voltage Input	2.2	3.7	4.5	V	
LDO_IN	Charger Voltage	4.5	5.0	5.5	V	V
V <sub>3.3</sub>	Voltage output	2.2	3.0	3.4	V	VBAT = 4.2V, 100mA loading
$V_{BT\_AVDD}$	Voltage output	1.2	1.25	1.35	V	VBAT=4.2V, 100mA loading
I <sub>L3.3</sub>	Loading current	_	_/	150	mA	VBAT = 4.2V

## 2.3 Battery Charge

Table 2-3

Symbol	Parameter	Min	Тур	Max	Unit	<b>Test Conditions</b>
LDO_IN	Charge Input Voltage	4.5	5	5.5	V	1
$V_{\text{Charge}}$	Charge Voltage	4.15	4.2	4.25	V	ı
$I_{Charge}$	Charge Current	20		200	mA	Charge current at fast charge mode
$I_{Trikl}$	Trickle Charge Current	20	45	70	mA	$V_{BAT} < V_{Trikl}$

## 2.4 IO Input/Output Electrical Logical Characteristics

Table 2-4

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
$V_{\rm IL}$	Low-Level Input Voltage	-0.3	-	0.3* VDDIO	V	VDDIO = 3.3V
$V_{\mathrm{IH}}$	High-Leve <mark>l Input</mark> Voltage	0.7* VDDIO	_	VDDIO+0.3	V	VDDIO = 3.3V
IO output	characteristi <mark>cs</mark>					
$V_{OL}$	Low-Level Output Voltage	-	<sup>71</sup> –	0.33	V	VDDIO = 3.3V
$V_{OH}$	High-Level Output Voltage	2.7	_	7-/	V	VDDIO = 3.3V

## 2.5 Internal Resistor Characteristics

Table 2-5

	Port	General Output	High Drive	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
	PA3, PB1,PB4, PB6~PB8, PC4,PC5, PD5,PD6,	8mA	24mA	10K	10K	1. PB1 default pull up 2. USBDM & USBDP default pull down
1	USBDP	4mA	-	1.5K	15K	3、internal pull-up/pull-down resistance   accuracy ±20%
	USBDM	4mA	_	180K	15K	

## 2.6 BT Characteristics

### 2.6.1 Transmitter

**Basic Data Rate** 

Table 2-6

Paramete	r	Min	Тур	Max	Unit	<b>Test Conditions</b>
RF Transmit P	ower		6	8	dBm	
RF Power Contro	l Range		20		dB	25℃,
20dB Bandwidth			950		KHz	Power Supply
	+2MHz		-40		dBm	
Adjacent Channel	-2MHz		-38		dBm	VBAT=5V
Transmit Power	+3MHz		-44		dBm	2441MHz
	-3MHz		-35		dBm	

### **Enhanced Data Rate**

Table 2-7

Paramete	Parameter			Max	Unit	Test Conditions
Relative Po		-1		dB		
π/4 DQPSK	DEVM RMS		6		%	
	DEVM 99%		10		%	25℃,
Modulation Accuracy	DEVM Peak		15		%	Power Supply
	+2MHz		-40		dBm	VBAT=5V
Adjacent Channel	-2MHz		-38		dBm	2441MHz
Transmit Power	+3MHz		-44		dBm	
	-3MHz		-35		dBm	

### 2.6.2 Receiver

### **Basic Data Rate**

Table 2-8

Paramete	Min	Тур	Max	Unit	<b>Test Conditions</b>	
Sensitivit	Sensitivity				dBm	
Co-channel Interferer	nce Rejection		-13		dB	
	+1MHz		+5		dB	25℃,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz	T I	+37		dB	VBAT=5V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz	7/1	+40		dB	
	-3MHz	77	+35	y	dB	

### **Enhanced Data Rate**

Table 2-9

Paramete	Parameter			Max	Unit	Test Conditions
Sensitivit	Sensitivity				dBm	
Co-channel Interferer	Co-channel Interference Rejection				dB	15
4/1/	+1MHz		+5		dB	25℃,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VBAT=5V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz		+35		dB	

# 3. Package Information

## 3.1 QFN20\_3.0x3.0

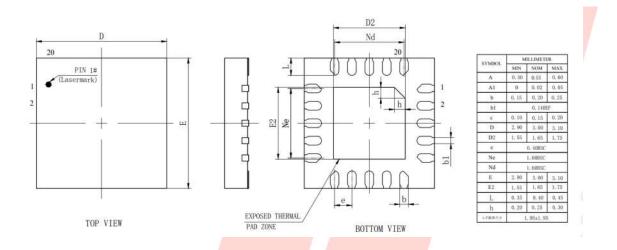


Figure 3-1 AC6373B Package

## 4. Revision History

Date	Revision	Description
2020.09.16	V1.0	Initial Release

